Sheet	7	of	1	

***************************************	Substitute Form PTO-1449 (Modified)	U.S. Department of Commerce Patent and Trademark Office	Attorney's Docket No. 10559-586003	Application No. 10/802,991	
***************************************	Information Disclosure Statement by Applicant (Use several sheets if necessary) (37 CFR §1.98(b))		Applicant Lawrence D. Wong		
*************			Filing Date March 16, 2004	Group Art Unit 1792	

U.S. Patent Documents							
Examiner Initial	Desig. ID AA	Document Number	Publication Date	Patentee	Class	Subclass	Filing Date If Appropriate
	AB						
	AC						

	Foreign Patent Documents or Published Foreign Patent Applications							
Examiner	Desig.	Document	Publication	Country or			Trans	lation
Initial	ID	Number	Date	Patent Office	Class	Subclass	Yes	No
	AD							
	AE							
	AF							

	Other D	ocuments (include Author, Title, Date, and Place of Publication)
Examiner Initial	Desig. ID	Document
	AG	Baklanov, M.R., et al., "Comparative study of Porous SOG Films with Different Non-Destructive Instrumentation", <i>Proceedings of the IEEE 2001 International Interconnect Technology Conference</i> , pp. 189-191, June 2001.
	AH	Drage, J.S., et al., "Effects of Electron Beam Exposure on Poly(arylene Ether) Dielectric Films", Mat. Res. Soc. Symp. Proc.: Low-Dielectric Constant Materials III, vol. 476, pp. 121-128, April 1997.
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Examiner Signature	Date Considered
EXAMINER: Initials citation considered. Draw line through citation if no	t in conformance and not considered, include copy of this form with
next communication to applicant.	